

NOT RECOMMENDED FOR NEW DESIGN USE DMP3007LSS



DMG4413LSS

30V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D max T _A = +25°C		
-30V	$7.5 \text{m}\Omega$ @ $V_{GS} = -10V$	-12A		
-307	$10.2 \text{m}\Omega$ @ $V_{GS} = -4.5V$	-10A		

Description

This MOSFET has been designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

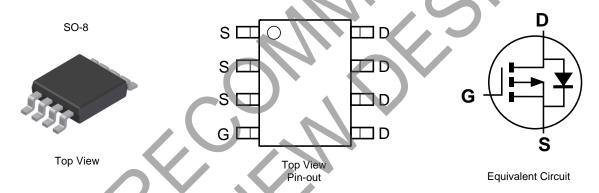
- Backlighting
- Power Management Functions
- DC-DC Converters

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (<u>DMG4413LSSQ</u>)

Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Lead Frame. Solderable per MIL-STD-202, Method 208 ©3
- Weight: 0.074 grams (Approximate)



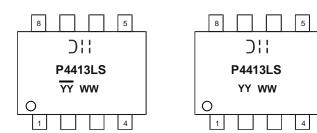
Ordering Information (Note 4)

Part Number	Case	Packaging
DMG4413LSS-13	SO-8	2500/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- B. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



Shanghai A/T Site

);; = Manufacturer's Marking
P4413LS = Product Type Marking Code
YYWW = Date Code Marking
YY or YY = Year (ex: 18 = 2018)
WW = Week (01 to 53)

YY = Date Code Marking for SAT (Shanghai Assembly/ Test Site)
YY = Date Code Marking for CAT (Chengdu Assembly/ Test Site)

Chengdu A/T Site



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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		V _{DSS}	-30	V	
Gate-Source Voltage		V _{GSS}	±20	V	
Continuous Dusis Courset (Note CVV	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-12 -10	А
Continuous Drain Current (Note 6) V _{GS} = -10V	t<10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-22 -17	А
Continuous Drain Current (Note 6) V	Steady State	$T_A = +25$ °C $T_A = +70$ °C	I _D	-10 -8	Α
Continuous Drain Current (Note 6) V _{GS} = -4.5V	t<10s	$T_A = +25$ °C $T_A = +70$ °C	ID	-18 -14	А
Pulsed Drain Current (10µs Pulse, Duty Cycle =	1%)	I _{DM}	-45	Α	
Maximum Body Diode Continuous Current	Is	-4	Α		

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	P _D	1.7	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State t<10s	Reja	74 22	°C/W
Total Power Dissipation (Note 6)	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	P _D	2.2	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State t<10s	R _{0JA}	56 17	°C/W
Thermal Resistance, Junction to Case (Note 6)	Steady State	R ₀ JC	2.5	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

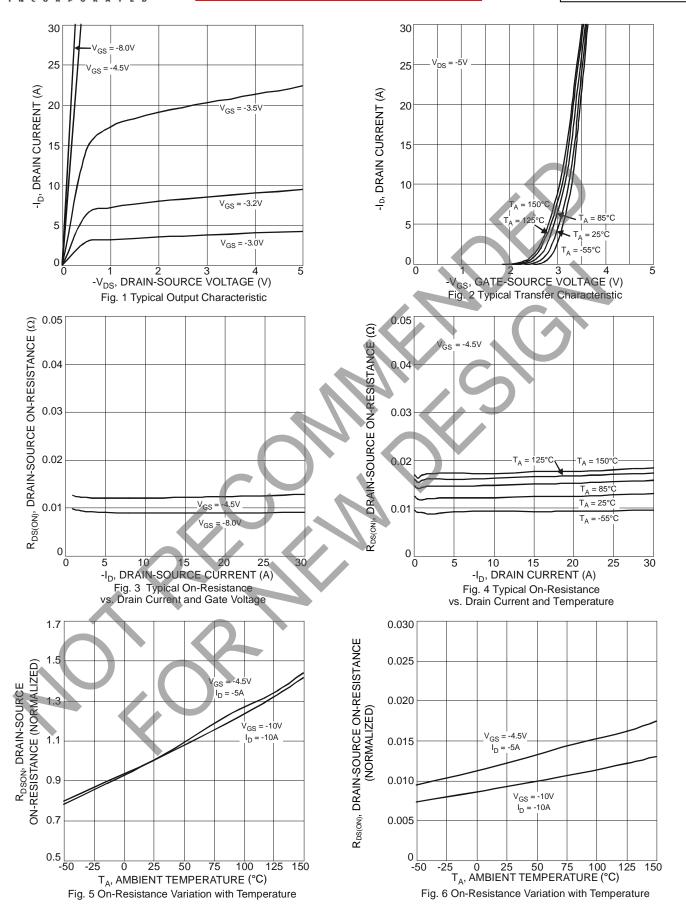
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV_{DSS}	-30		_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS		_	-1	μΑ	$V_{DS} = -30V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}		_	±1	μΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	-1.1	-1.6	-2.1	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance			6.3	7.5	mΩ	$V_{GS} = -10V, I_D = -13A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	7.9	10.2	1112.2	$V_{GS} = -4.5V$, $I_{D} = -10A$	
Forward Transconductance	9 _{fs}	_	26	_	S	$V_{DS} = -15V, I_D = -13A$	
Diode Forward Voltage	V_{SD}	_	-0.7	-1.0	V	$V_{GS} = 0V, I_{S} = -2.7A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}		4965		pF	15)/)/ 0)/	
Output Capacitance	Coss		1487		pF	$V_{DS} = -15V, V_{GS} = 0V$ f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	711	_	pF	1 = 1.000112	
Gate Resistance	R_{G}	_	7.3	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$ f = 1.0MHz	
SWITCHING CHARACTERISTICS (Note 8)							
Total Gate Charge	Q_{G}		46			$V_{DS} = -15V, V_{GS} = -5V$ $I_{D} = -13A$	
Gate-Source Charge	Q_{GS}	_	17	_	nC		
Gate-Drain Charge	Q_{GD}	_	16	_			
Turn-On Delay Time	t _{D(ON)}		15	_		V _{DS} = -15V, V _{GS} = -10V,	
Rise Time	t _R	_	9	_	20		
Turn-Off Delay Time	t _{D(OFF)}	_	160	_	ns	$I_D = -1A, R_G = 6.0\Omega$	
Fall Time	t _F	_	66	_			

Notes:

- Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.







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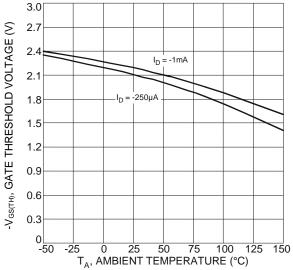
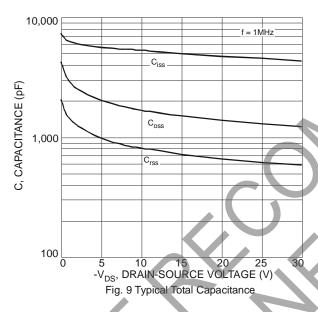
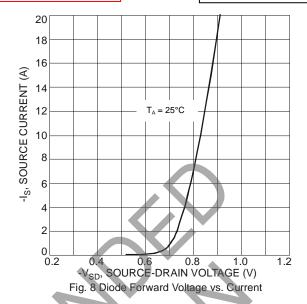
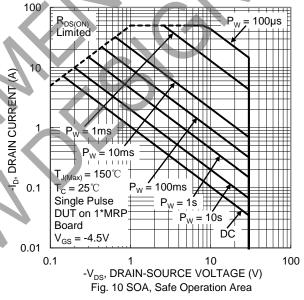


Fig. 7 Gate Threshold Variation vs. Ambient Temperature





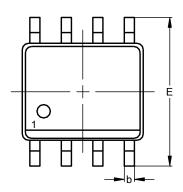


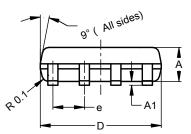


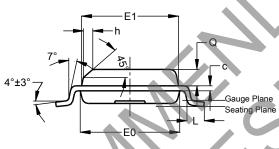
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8





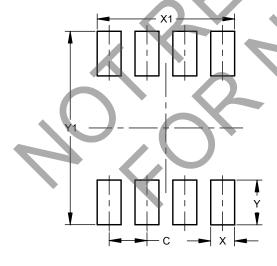


SO-8					
Dim	Min	Max	Тур		
Α	1.40	1.50	1.45		
A1	0.10	0.20	0.15		
b	0.30	0.50	0.40		
C	0.15	0.25	0.20		
D	4.85	4.95	4.90		
E	5.90	6.10	6.00		
E1	3.80	3.90	3.85		
E0	3.85	3.95	3.90		
е			1.27		
h	1		0.35		
L	0.62	0.82	0.72		
Q	0.60	0.70	0.65		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8



Dimensions	Value (in mm)		
С	1.27		
Х	0.802		
X1	4.612		
Y	1.505		
V1	6.50		



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